

## **AME8807**

## **600mA CMOS LDO**

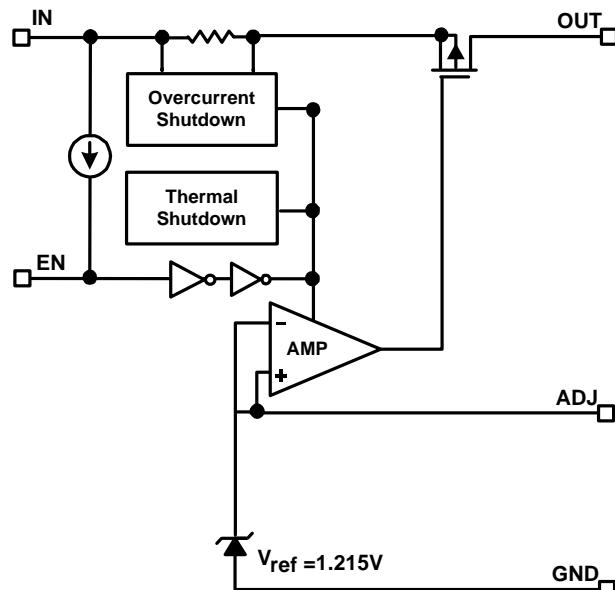
### **■ General Description**

The AME8807 family of positive, linear regulators feature low ground current ( $30\mu\text{A}$  Typ.) with low dropout voltage, making them ideal for battery applications. The space-saving SOP-8 & DFN-8 (3mmx3mmx0.75mm) packages are attractive for "Pocket" and "Hand Held" applications.

These rugged devices have both Thermal Shutdown, and Current Fold-back to prevent device failure under the "Worst" operating conditions.

The AME8807 is stable with an output capacitance of  $2.2\mu\text{F}$  or greater.

### **■ Functional Block Diagram**



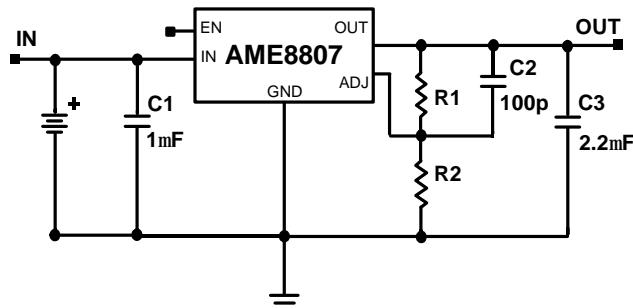
### **■ Features**

- Very Low Dropout Voltage
- Guaranteed 600mA Output
- Typical  $30\mu\text{A}$  Quiescent Current
- Accurate to within 1.5%
- Over-Temperature Shutdown
- Current Limiting
- Short Circuit Current Fold-back
- Power-Saving Shutdown Mode
- Space-Saving SOP-8 & DFN-8 (3mmx3mmx0.75mm) Packages
- User Adjustable Output Voltages
- Low Temperature Coefficient
- All AME's Lead Free Products Meet RoHS Standards

### **■ Applications**

- Instrumentation
- Portable Electronics
- Wireless Devices
- Cordless Phones
- PC Peripherals
- Battery Powered Widgets

### **■ Typical Application**



$$V_{\text{OUT}} = 1.215 \left( \frac{R_1}{R_2} + 1 \right)$$

C2 is unnecessary if  $R_1$  or  $R_2 < 20$  K Ohms

$R_1$  and  $R_2$  use resistance value within 1% accuracy for correct  $V_{\text{OUT}}$

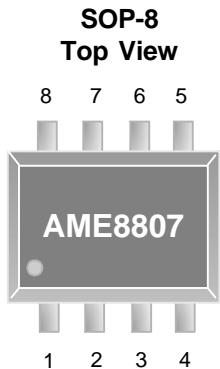


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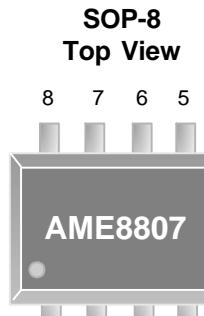
**600mA CMOS LDO**

## ■ Pin Configuration



**AME8807AEHA**

1. IN
2. GND
3. GND
4. EN
5. ADJ
6. GND
7. GND
8. OUT



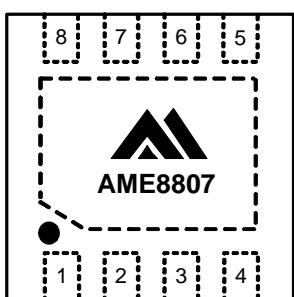
**AME8807BEHA**

1. OUT
2. ADJ
3. GND
4. NC
5. EN
6. NC
7. NC
8. IN

\* Die Attach:  
Conductive Epoxy

\* Die Attach:  
Conductive Epoxy

DFN-8  
(3mmx3mmx0.75mm)  
Top View



**AME8807AEVA**

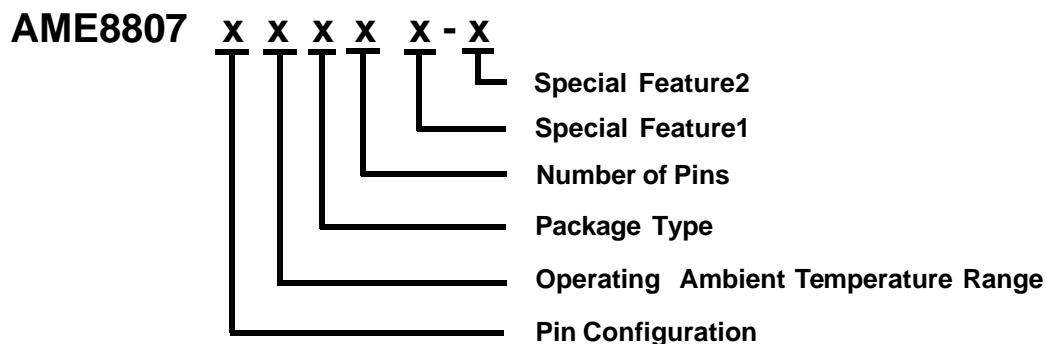
1. EN
2. GND
3. GND
4. IN
5. OUT
6. GND
7. GND
8. ADJ

\* Die Attach:  
Conductive Epoxy

**Note:**

The area enclosed by dashed line represents Exposed Pad and connect to GND.

## ■ Ordering Information



Pin Configuration	Operating Ambient Temperature Range	Package Type	Number of Pins	Special Feature1	Special Feature 2 (For DFN package only)
A: 1. IN (SOP-8) 2. GND 3. GND 4. EN 5. ADJ 6. GND 7. GND 8. OUT  B: 1. OUT (SOP-8) 2. ADJ 3. GND 4. NC 5. EN 6. NC 7. NC 8. IN  A: 1. EN (DFN-8) 2. GND 3. GND 4. IN 5. OUT 6. GND 7. GND 8. ADJ	E: -40°C to 85°C	H: SOP V: DFN	A: 8	Z: Lead Free	3: 3x3x0.75(mm) (LxWxH)



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**AME8807**

**600mA CMOS LDO**

## ■ Ordering Information

Part Number	Marking*	Output Voltage	Package	Operating Ambient Temperature Range
AME8807AEHA	8807 AEHA yyww	Adjustable	SOP-8	- 40°C to 85°C
AME8807AEHAZ	8807 AEHA yyww	Adjustable	SOP-8	- 40°C to 85°C
AME8807BEHA	8807 BEHA yyww	Adjustable	SOP-8	- 40°C to 85°C
AME8807BEHAZ	8807 BEHA yyww	Adjustable	SOP-8	- 40°C to 85°C
AME8807AEVAZ-3	BEX yyww	Adjustable	DFN-8 (3mmx3mmx0.75mm)	- 40°C to 85°C

Note: yyww represents the date code

\* A line on top of the first letter represents lead free plating such as 8807

Please consult AME sales office or authorized Rep./Distributor for package type availability.

## ■ Absolute Maximum Ratings

Parameter	Maximum	Unit
Input Voltage	-0.3 to 8	V
EN Voltage	-0.3 to 8	V
Output Voltage	-0.3 to $V_{IN} + 0.3$	V
Output Current	$P_D / (V_{IN} - V_{OUT})$	mA
ESD Classification	B*	

Caution: Stress above the listed absolute maximum rating may cause permanent damage to the device.

\*HBM B:2000V~3999V

## ■ Recommended Operating Conditions

Parameter	Symbol	Rating	Unit
Ambient Temperature Range	$T_A$	- 40 to 85	°C
Junction Temperature Range	$T_J$	- 40 to 125	°C
Storage Temperature Range	$T_{STG}$	- 65 to 150	°C

## ■ Thermal Information

Parameter	Package	Die Attach	Symbol	Maximum	Unit		
Thermal Resistance* (Junction to Case)	SOP-8		$\theta_{JC}$	60	°C / W		
	DFN-8 (3mmx3mmx0.75mm)			17			
Thermal Resistance (Junction to Ambient)	SOP-8		$\theta_{JA}$	150			
	DFN-8 (3mmx3mmx0.75mm)			125			
Internal Power Dissipation	SOP-8		$P_D$	810	mW		
	DFN-8 (3mmx3mmx0.75mm)			800			
Maximum Junction Temperature				150	°C		
Solder Iron (10 Sec)**				350	°C		

\* Measure  $\theta_{JC}$  on center of molding compound if IC has no tab.

\*\* MIL-STD-202G 210F



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AME8807

600mA CMOS LDO

## ■ Electrical Specifications

$T_A = 25^\circ\text{C}$  unless otherwise noted

Parameter	Symbol	Test Condition		Min	Typ	Max	Units
Input Voltage	$V_{IN}$			Note 1		7	V
Output Voltage Accuracy	$V_O$	$I_O = 1\text{mA}$		-1.5		1.5	%
Dropout Voltage	$V_{DROPOUT}$	$I_O = 600\text{mA}$ $V_O = V_{O(NOM)} - 2.0\%$	1.5V < $V_{O(NOM)}$ <= 2.0V		See chart	1400	mV
			2.0V < $V_{O(NOM)}$ <= 2.8V			800	
			2.8V < $V_{O(NOM)}$			600	
Output Current	$I_O$	$V_O > 1.2\text{V}$		600			mA
Current Limit	$I_{LM}$	$V_O > 1.2\text{V}$		600	800		mA
Short Circuit Current	$I_{SC}$	$V_O < 0.8\text{V}$			300	600	mA
Quiescent Current (For Fixed Output Voltage Options)	$I_Q$	$I_O = 0\text{mA}$			30	50	$\mu\text{A}$
Ground Pin Current	$I_{GND}$	$I_O = 1\text{mA to } 600\text{mA}$			30		$\mu\text{A}$
Line Regulation	$REG_{LINE}$	$I_O = 1\text{mA}$ $V_{IN} = V_O + 1 \text{ to } V_O + 2$	$V_O < 2.0\text{V}$			0.15	%
			$V_O \geq 2.0\text{V}$		0.02	0.1	%
Load Regulation	$REG_{LOAD}$	$I_O = 1\text{mA to } 600\text{mA}$			0.2	1	%
Over Temperature Shutdown	OTS				150		$^\circ\text{C}$
Over Temperature Hysteresis	OTH				30		$^\circ\text{C}$
$V_O$ Temperature Coefficient	TC				30		$\text{ppm}/^\circ\text{C}$
Power Supply Rejection	PSRR	$I_O = 100\text{mA}$ $C_O = 2.2\mu\text{F}$	$f = 1\text{kHz}$		50		dB
			$f = 10\text{kHz}$		20		
			$f = 100\text{kHz}$		15		
Output Voltage Noise	eN	$f = 10\text{Hz to } 100\text{kHz}$ $I_O = 10\text{mA}$	$C_O = 2.2\mu\text{F}$		30		$\mu\text{VRms}$
ADJ Reference Voltage	$V_{REF}$			1.203	1.215	1.227	V
EN Input Threshold	$V_{EH}$	$V_{IN} = 2.7\text{V to } 7\text{V}$		2.0		$V_{in}$	V
	$V_{EL}$	$V_{IN} = 2.7\text{V to } 7\text{V}$		0		0.4	V
EN Input Bias Current	$I_{EH}$	$V_{EN} = V_{IN}, V_{IN} = 2.7\text{V to } 7\text{V}$				0.1	$\mu\text{A}$
	$I_{EL}$	$V_{EN} = 0\text{V}, V_{IN} = 2.7\text{V to } 7\text{V}$				0.5	$\mu\text{A}$
Shutdown Supply Current	$I_{SD}$	$V_{IN} = 5\text{V}, V_O = 0\text{V}, V_{EN} < V_{EL}$			0.5	1	$\mu\text{A}$

Note 1:  $V_{IN(\min)} = V_{OUT} + V_{DROPOUT}$



## ■ Detailed Description

The AME8807 family of CMOS regulators contain a PMOS pass transistor, voltage reference, error amplifier, over-current protection, and thermal shutdown.

The P-channel pass transistor receives data from the error amplifier, over-current shutdown, and thermal protection circuits. During normal operation, the error amplifier compares the output voltage to a precision reference. Over-current and Thermal shutdown circuits become active when the junction temperature exceeds 150°C, or the current exceeds 600mA. During thermal shutdown, the output voltage remains low. Normal operation is restored when the junction temperature drops below 120°C.

The AME8807 switches from voltage mode to current mode when the load exceeds the rated output current. This prevents over-stress. The AME8807 also incorporates current fold-back to reduce power dissipation when the output is short circuited. This feature becomes active when the output drops below 0.8 volts, and reduces the current flow by 65%. Full current is restored when the voltage exceeds 0.8 volts.

## ■ External Capacitors

The AME8807 is stable with an output capacitor to ground of 2.2 $\mu$ F or greater. Ceramic capacitors have the lowest ESR, and will offer the best AC performance. Conversely, Aluminum Electrolytic capacitors exhibit the highest ESR, resulting in the poorest AC response. Unfortunately, large value ceramic capacitors are comparatively expensive. One option is to parallel a 0.1 $\mu$ F ceramic capacitor with a 10 $\mu$ F Aluminum Electrolytic. The benefit is low ESR, high capacitance, and low overall cost.

A second capacitor is recommended between the input and ground to stabilize Vin. The input capacitor should be at least 0.1 $\mu$ F to have a beneficial effect.

All capacitors should be placed in close proximity to the pins. A "Quiet" ground termination is desirable. This can be achieved with a "Star" connection.

## ■ Enable

The Enable pin normally floats high. When actively pulled low, the PMOS pass transistor shuts off, and all internal circuits are powered down. In this state, the quiescent current is less than 1 $\mu$ A. This pin behaves much like an electronic switch.

## ■ ADJ

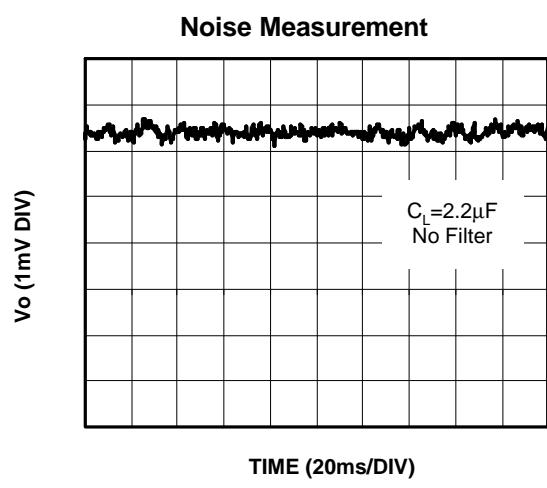
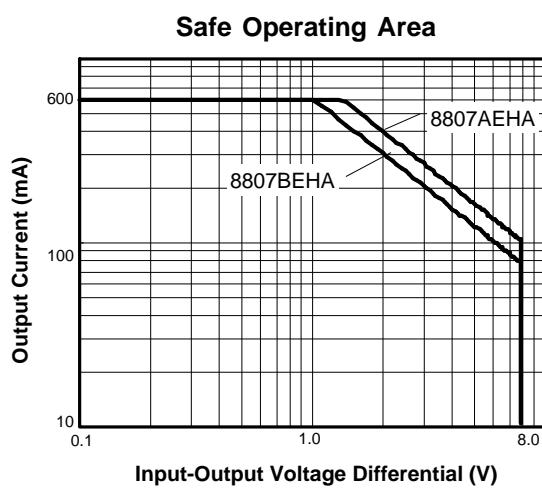
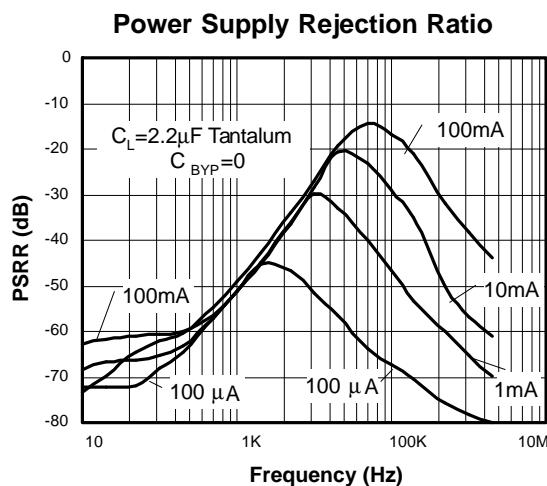
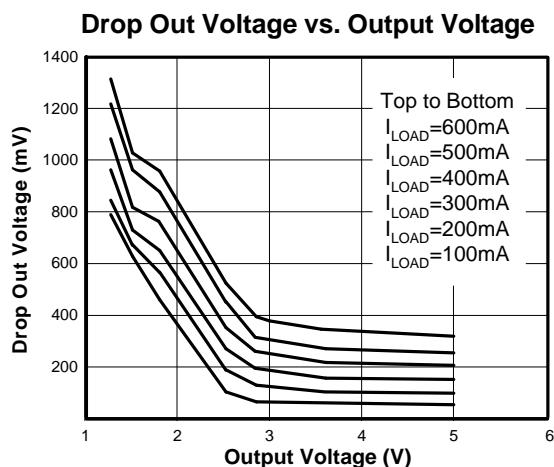
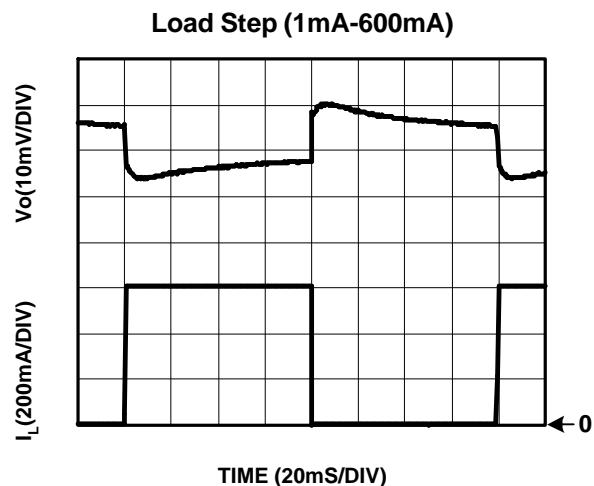
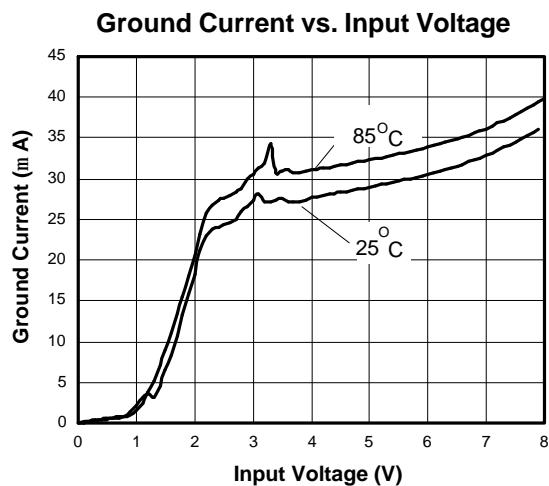
The ADJ pin is the positive input to the error amplifier which, due to the pmos pass element inversion, means it is actually the negative input of the LDO feedback loop. The feedback works to keep the voltage at the ADJ pin 1.215V with respect to ground. Since the internal circuitry at the ADJ pin is essentially an ESD protected CMOS gate the input current at the ADJ pin is virtually zero.



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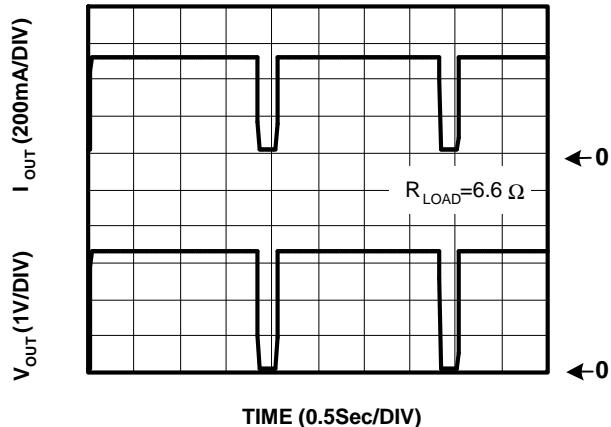


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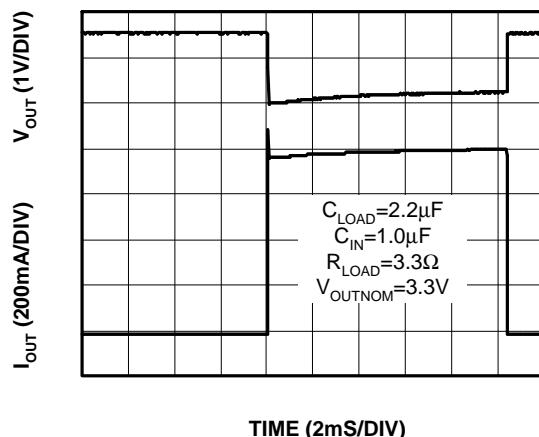
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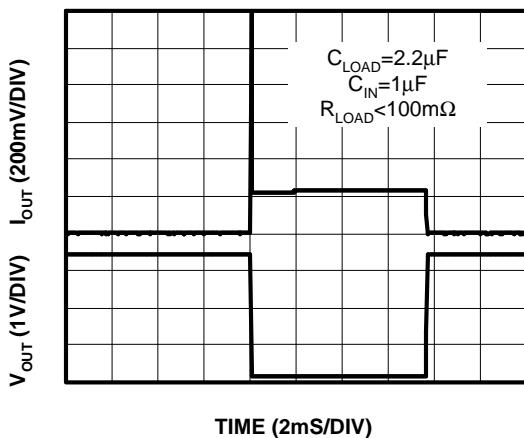
#### Overtemperature Shutdown



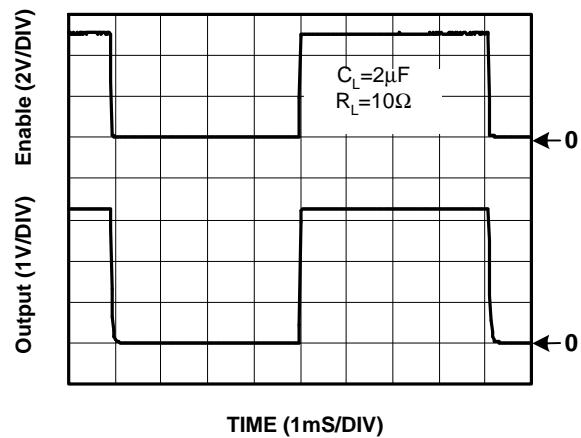
#### Current Limit Response



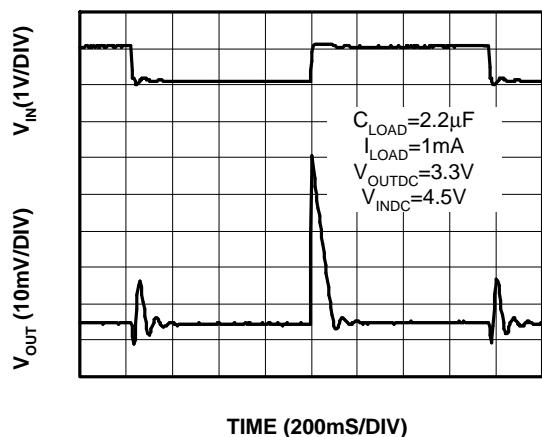
#### Short Circuit Response



#### Chip Enable Transient Response



#### Line Transient Response



**■ External Resistor Divider Table**

R1 (K Ohm)	1	2	3	4	5	6	7	8	9	10
Vout	R2(K Ohm)=(1.215*R1(K Ohm))/(Vout-1.215)									
1.30	14.29	28.59	42.88	57.18	71.47	85.76	100.06	114.35	128.65	142.94
1.35	9.00	18.00	27.00	36.00	45.00	54.00	63.00	72.00	81.00	90.00
1.40	6.57	13.14	19.70	26.27	32.84	39.41	45.97	52.54	59.11	65.68
1.45	5.17	10.34	15.51	20.68	25.85	31.02	36.19	41.36	46.53	51.70
1.50	4.26	8.53	12.79	17.05	21.32	25.58	29.84	34.11	38.37	42.63
1.55	3.63	7.25	10.88	14.51	18.13	21.76	25.39	29.01	32.64	36.27
1.60	3.16	6.31	9.47	12.62	15.78	18.94	22.09	25.25	28.40	31.56
1.65	2.79	5.59	8.38	11.17	13.97	16.76	19.55	22.34	25.14	27.93
1.70	2.51	5.01	7.52	10.02	12.53	15.03	17.54	20.04	22.55	25.05
1.75	2.27	4.54	6.81	9.08	11.36	13.63	15.90	18.17	20.44	22.71
1.80	2.08	4.15	6.23	8.31	10.38	12.46	14.54	16.62	18.69	20.77
1.85	1.91	3.83	5.74	7.65	9.57	11.48	13.39	15.31	17.22	19.13
1.90	1.77	3.55	5.32	7.09	8.87	10.64	12.42	14.19	15.96	17.74
1.95	1.65	3.31	4.96	6.61	8.27	9.92	11.57	13.22	14.88	16.53
2.00	1.55	3.10	4.64	6.19	7.74	9.29	10.83	12.38	13.93	15.48
2.05	1.46	2.91	4.37	5.82	7.28	8.73	10.19	11.64	13.10	14.55
2.10	1.37	2.75	4.12	5.49	6.86	8.24	9.61	10.98	12.36	13.73
2.15	1.30	2.60	3.90	5.20	6.50	7.80	9.10	10.40	11.70	12.99
2.20	1.23	2.47	3.70	4.93	6.17	7.40	8.63	9.87	11.10	12.34
2.25	1.17	2.35	3.52	4.70	5.87	7.04	8.22	9.39	10.57	11.74
2.30	1.12	2.24	3.36	4.48	5.60	6.72	7.84	8.96	10.08	11.20
2.35	1.07	2.14	3.21	4.28	5.35	6.42	7.49	8.56	9.63	10.70
2.40	1.03	2.05	3.08	4.10	5.13	6.15	7.18	8.20	9.23	10.25
2.45	0.98	1.97	2.95	3.94	4.92	5.90	6.89	7.87	8.85	9.84
2.50	0.95	1.89	2.84	3.78	4.73	5.67	6.62	7.56	8.51	9.46
2.55	0.91	1.82	2.73	3.64	4.55	5.46	6.37	7.28	8.19	9.10
2.60	0.88	1.75	2.63	3.51	4.39	5.26	6.14	7.02	7.90	8.77
2.65	0.85	1.69	2.54	3.39	4.23	5.08	5.93	6.77	7.62	8.47
2.70	0.82	1.64	2.45	3.27	4.09	4.91	5.73	6.55	7.36	8.18
2.75	0.79	1.58	2.37	3.17	3.96	4.75	5.54	6.33	7.12	7.92
2.80	0.77	1.53	2.30	3.07	3.83	4.60	5.37	6.13	6.90	7.67
2.85	0.74	1.49	2.23	2.97	3.72	4.46	5.20	5.94	6.69	7.43
2.90	0.72	1.44	2.16	2.88	3.61	4.33	5.05	5.77	6.49	7.21
2.95	0.70	1.40	2.10	2.80	3.50	4.20	4.90	5.60	6.30	7.00
3.00	0.68	1.36	2.04	2.72	3.40	4.08	4.76	5.45	6.13	6.81
3.05	0.66	1.32	1.99	2.65	3.31	3.97	4.63	5.30	5.96	6.62
3.10	0.64	1.29	1.93	2.58	3.22	3.87	4.51	5.16	5.80	6.45



## ■ External Resistor Divider Table (contd.)

R1 (K Ohm)	1	2	3	4	5	6	7	8	9	10
Vout	$R2(K \text{ Ohm}) = (1.215 * R1(\text{K Ohm})) / (Vout - 1.215)$									
3.15	0.63	1.26	1.88	2.51	3.14	3.77	4.40	5.02	5.65	6.28
3.20	0.61	1.22	1.84	2.45	3.06	3.67	4.28	4.90	5.51	6.12
3.25	0.60	1.19	1.79	2.39	2.99	3.58	4.18	4.78	5.37	5.97
3.30	0.58	1.17	1.75	2.33	2.91	3.50	4.08	4.66	5.24	5.83
3.35	0.57	1.14	1.71	2.28	2.85	3.41	3.98	4.55	5.12	5.69
3.40	0.56	1.11	1.67	2.22	2.78	3.34	3.89	4.45	5.00	5.56
3.45	0.54	1.09	1.63	2.17	2.72	3.26	3.81	4.35	4.89	5.44
3.50	0.53	1.06	1.60	2.13	2.66	3.19	3.72	4.25	4.79	5.32
3.55	0.52	1.04	1.56	2.08	2.60	3.12	3.64	4.16	4.68	5.20
3.60	0.51	1.02	1.53	2.04	2.55	3.06	3.57	4.08	4.58	5.09
3.65	0.50	1.00	1.50	2.00	2.49	2.99	3.49	3.99	4.49	4.99
3.70	0.49	0.98	1.47	1.96	2.44	2.93	3.42	3.91	4.40	4.89
3.75	0.48	0.96	1.44	1.92	2.40	2.88	3.36	3.83	4.31	4.79
3.80	0.47	0.94	1.41	1.88	2.35	2.82	3.29	3.76	4.23	4.70
3.85	0.46	0.92	1.38	1.84	2.31	2.77	3.23	3.69	4.15	4.61
3.90	0.45	0.91	1.36	1.81	2.26	2.72	3.17	3.62	4.07	4.53
3.95	0.44	0.89	1.33	1.78	2.22	2.67	3.11	3.55	4.00	4.44
4.00	0.44	0.87	1.31	1.75	2.18	2.62	3.05	3.49	3.93	4.36
4.05	0.43	0.86	1.29	1.71	2.14	2.57	3.00	3.43	3.86	4.29
4.10	0.42	0.84	1.26	1.68	2.11	2.53	2.95	3.37	3.79	4.21
4.15	0.41	0.83	1.24	1.66	2.07	2.48	2.90	3.31	3.73	4.14
4.20	0.41	0.81	1.22	1.63	2.04	2.44	2.85	3.26	3.66	4.07
4.25	0.40	0.80	1.20	1.60	2.00	2.40	2.80	3.20	3.60	4.00
4.30	0.39	0.79	1.18	1.58	1.97	2.36	2.76	3.15	3.54	3.94
4.35	0.39	0.78	1.16	1.55	1.94	2.33	2.71	3.10	3.49	3.88
4.40	0.38	0.76	1.14	1.53	1.91	2.29	2.67	3.05	3.43	3.81
4.45	0.38	0.75	1.13	1.50	1.88	2.25	2.63	3.00	3.38	3.76
4.50	0.37	0.74	1.11	1.48	1.85	2.22	2.59	2.96	3.33	3.70
4.55	0.36	0.73	1.09	1.46	1.82	2.19	2.55	2.91	3.28	3.64
4.60	0.36	0.72	1.08	1.44	1.79	2.15	2.51	2.87	3.23	3.59
4.65	0.35	0.71	1.06	1.41	1.77	2.12	2.48	2.83	3.18	3.54
4.70	0.35	0.70	1.05	1.39	1.74	2.09	2.44	2.79	3.14	3.49
4.75	0.34	0.69	1.03	1.37	1.72	2.06	2.41	2.75	3.09	3.44
4.80	0.34	0.68	1.02	1.36	1.69	2.03	2.37	2.71	3.05	3.39
4.85	0.33	0.67	1.00	1.34	1.67	2.01	2.34	2.67	3.01	3.34
4.90	0.33	0.66	0.99	1.32	1.65	1.98	2.31	2.64	2.97	3.30
4.95	0.33	0.65	0.98	1.30	1.63	1.95	2.28	2.60	2.93	3.25
5.00	0.32	0.64	0.96	1.28	1.61	1.93	2.25	2.57	2.89	3.21



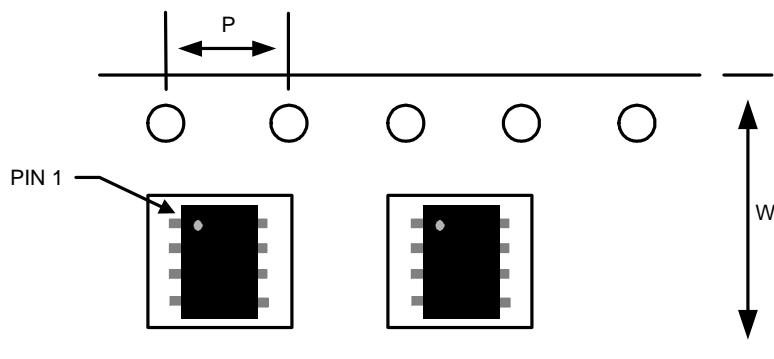
AME, Inc.

**AME8807**

**600mA CMOS LDO**

## ■ Tape and Reel Dimension

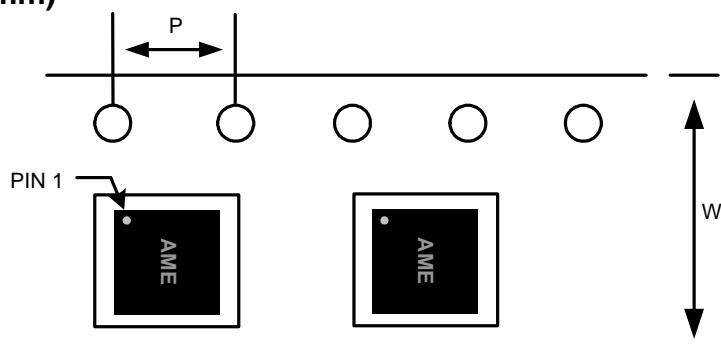
SOP-8



Carrier Tape, Number of Components Per Reel and Reel Size

Package	Carrier Width (W)	Pitch (P)	Part Per Full Reel	Reel Size
SOP-8	12.0±0.1 mm	4.0±0.1 mm	2500pcs	330±1 mm

**DFN-8**  
(3mmx3mmx0.75mm)



Carrier Tape, Number of Components Per Reel and Reel Size

Package	Carrier Width (W)	Pitch (P)	Part Per Full Reel	Reel Size
DFN-8 (3x3x0.75mm)	12.0±0.1 mm	4.0±0.1 mm	3000pcs	330±1 mm



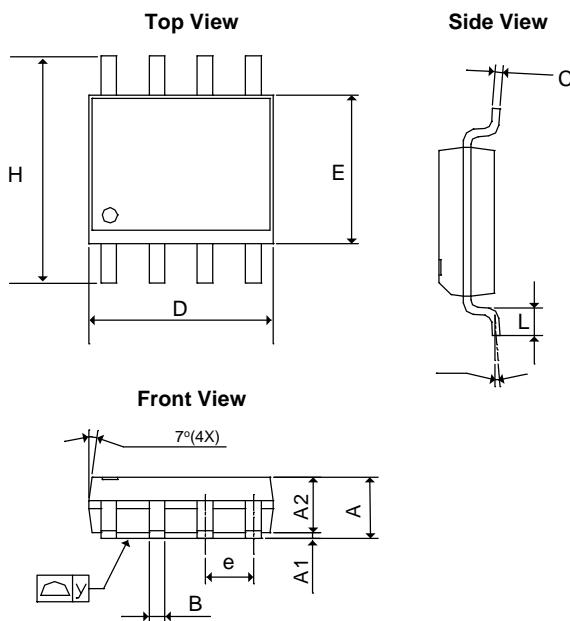
AME, Inc.

**AME8807**

**600mA CMOS LDO**

## ■ Package Dimension

**SOP-8**



SYMBOLS	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.35	1.75	0.05315	0.0689
A <sub>1</sub>	0.10	0.30	0.00394	0.01181
A2	1.473 REF		0.05799 REF	
B	0.33	0.51	0.01299	0.02008
C	0.19	0.25	0.00748	0.00984
D	4.80	5.33	0.18898	0.20984
E	3.80	4.00	0.14961	0.15748
e	1.27 BSC		0.05000 BSC	
L	0.40	1.27	0.01575	0.05000
H	5.80	6.30	0.22835	0.24803
y	-	0.10	-	0.00394
q	$0^\circ$		$8^\circ$	



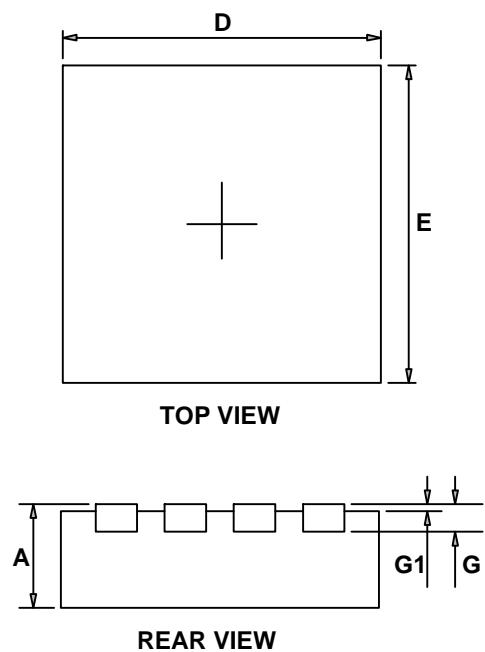
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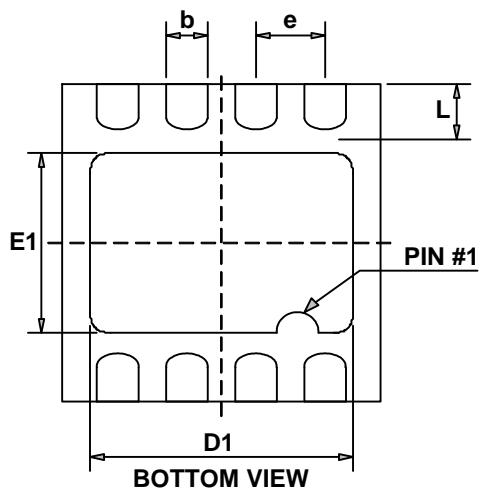
**600mA CMOS LDO**

## ■ Package Dimension

DFN-8 (3mmx3mmx0.75mm)



SYMBOLS	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.700	0.800	0.028	0.031
D	2.900	3.100	0.114	0.122
E	2.900	3.100	0.114	0.122
e	0.600	0.700	0.024	0.028
D1	2.200	2.400	0.087	0.094
E1	1.400	1.600	0.055	0.063
b	0.200	0.320	0.008	0.013
L	0.375	0.575	0.015	0.023
G	0.153	0.253	0.0060	0.010
G1	0.000	0.050	0.0000	0.002





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